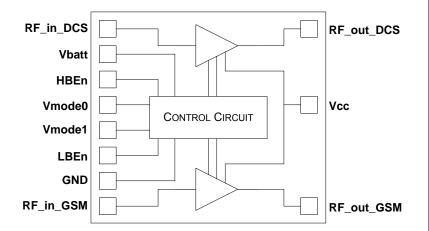


TQM7M5013

Data Sheet

Quad-Band GSM850/GSM900/DCS/PCS Advanced Input Power Controlled EDGE PAM



Functional Block Diagram

Product Description

The TQM7M5013 is an input power controlled, multiple gain state, guad band, GSM/EDGE PAM designed for use with the Qualcomm QTR/RTR8600 WEDGE solutions. This highly efficient PAM significantly improves talk-time while still providing an easy to use solution in a small form factor. The PA output power is controlled by the input power coming from the transceiver in both GMSK and 8PSK modes and so does not require a Vramp input. Additionally, the small 5mm x 5mm package requires minimum board space and allows for high levels of phone integration.

Electrical Specifications¹

Parameter	GSM850	GSM900	DCS	PCS	Units
	Тур	Тур	Тур	Тур	
GMSK HPM Pout	35.3	35	33.3	33	dBm
GMSK MPM Pout	31.8	32.2	-	-	dBm
8PSK (RMS Power)	29	29	28	28	dBm
GMSK LPM Pout	22	22	22.8	22	dBm
GMSK ULPM Pout	20.5	21	21.5	20	dBm
GMSK HPM PAE	52	55	55	52	%
GMSK MPM PAE	43	45	-	-	%
GMSK LPM PAE	27	31	25	19	%
GMSK ULPM PAE	29	32	23	16	%

Note 1: RF performance measured at standard operating conditions.

Data Sheet

For additional information and the latest specifications, see our website: www.triguint.com Revision P, August 31, 2011

Features

- For Quad Band GSM/EDGE .
- **Digital Control Interface**
- Low Current at Backed-off Power Levels •
- Input power controlled GMSK and 8PSK
- LB has 4 modes HP, MP, LP, and ULP •
- HB has 3 modes HP, LP, and ULP •
- HBT/PHEMT High Efficient Technology •
- High–Power Linearity •
- Standard LB and HB paths
- 50Ω input and Output Impedance •
- Halogen-free •
- 11 Pin Package

Applications

- **GSM/EDGE/WEDGE Handsets**
- GSM/EDGE/WEDGE Wireless Cards

Package Style

